## **Electronic supplementary information**

## Cooperative tin oxide fullerene electron selective layers for

## high-performance planar perovskite solar cells

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**Fig. S1** (a) Schematic view and (b) energy band diagram of a planar perovskite solar cell using a SnO<sub>2</sub>/PCBM ESL.



**Fig. S2** (a) UV-vis absorbance spectrum, (b) *J-V* curves, and (c) EQE spectrum of a perovskite solar cell using a PCBM ESL.



Fig. S3 XRD patterns of perovskite films grown on SnO<sub>2</sub> and SnO<sub>2</sub>/PCBM ESLs.



**Fig. S4** (a) *J-V* curves of the cells using SnO<sub>2</sub>/PCBM ESLs with PCBM films preprared by the precursors containing 5, 10, and 15 mg/mL PCBM in dichlorobenzene solutions measured under reverse voltage scanning.

**Table S1** Summary of the photovoltaic parameters of the cells using SnO2/PCBM ESLs withPCBM films preprared by different PCBM concentrations in dichlorobenzene solutionsmeasured under reverse voltage scanning.

PCBM Concentration	$V_{ m oc}$	$J_{ m sc}$	FF	PCE
[mg/mL]	[V]	$[mA cm^{-2}]$	[%]	[%]
5	1.10	21.00	77.11	17.77
10	1.10	21.22	77.52	18.08
15	1.08	20.63	77.65	17.26

**Table S2** Values for TRPL characteristics of perovskite films deposited on  $SnO_2$  and $SnO_2$ /PCBM ESLs.

	$\tau_1$	Ratio	$\tau_2$	Ratio
	[ns]	[%]	[ns]	[%]
SnO <sub>2</sub> ESL	0.07	93.77	0.83	6.23
SnO <sub>2</sub> /PCBM ESL	0.06	95.46	0.33	4.54



Fig. S5 Nyquist plots of the cells using unpassivated SnO<sub>2</sub> and SnO<sub>2</sub>/PCBM ESLs.



**Fig. S6** *J-V* curve of the planar perovskite solar cell using a  $SnO_2$  ESL with a 5 nm thick  $C_{60}$  film measured under reverse voltage scanning.